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TI Semiconducting compositions and electric cables
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CLASS

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AB A semiconducting compn. consists of a mixt. of an ethylenevinyl acetate-PVC graft **polymer** and ethylenevinyl acetate (blending ratio of 90/10-20/80) which is mixed with an elec. cond. agent 100 wt. parts, and Ca aluminate 0.5-20 wt. parts. Elec. cables using the compn. in external semiconducting layers have excellent thermal resistance and surface smoothness.

ST semiconductor compn elec cable
IT Semiconductor materials
IT (compns., for elec. cables)
IT Electric cables